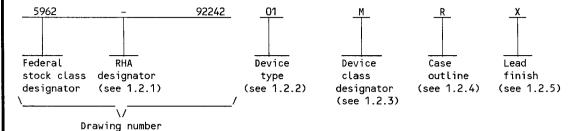
THIS REVIS	ION DES		OF REVISION AS BEEN AUTH	ON (NOR) ORIZED FOR THE DO	OCUMENT LISTED.	1. DATE (YYMMDD) 96-09-06	Form Approved OMB No. 0704-0188
Public reporting b gathering and ma aspect of this coll	urden for this intaining the ection of infor	collection is estimated to a data needed, and completi mation, including suggest	verage 2 hours per re ng and reviewing the ons for reducing this	sponse, including the time for collection of information. Send burden, to Department of De	reviewing instructions, sear I comments regarding this b fense, Washington Headqu	ching existing data sources, urden estimate or any other arters Services, Directorate	2. PROCURING ACTIVITY NO.
Paperwork Redu PLEASE DO NO ISSUING CONTI	perations ar ction Project OT RETURN RACTING O	nd Reports, 1215 Jefferso (0704-0188), Washingtor YOUR COMPLETED FO FFICER FOR THE CONT	n Davis Highway, Su 1, DC 20503. PRM TO EITHER OF RACT/ PROCURING	sponse, including the time for collection of information. Sent burden, to Department of De site 1204, Arlington, VA 2220; THESE ADDRESSED. RES ACTIVITY NUMBER LISTE	TURN COMPLETED FORI D IN ITEM 2 OF THIS FOR	r Management and Budget, M TO THE GOVERNMENT M.	3. DODAAC
4. ORIGINAT	OR		Defense Sup	Street, City, State, Zip	•	5. CAGE CODE 67268	6. NOR NO. 5962-R202-96
a. TYPED NA Last)	AME (Firs	t, Middle Initial,	3990 East Br Columbus, C	road Street 0H 43216-5000		7. CAGE CODE 67268	8. DOCUMENT NO. 5962-92242
	IRCUIT, E	DIGITAL, FAST CM			10. REVISION LET	TER	11. ECP NO.
	AND LIMI	TING THREE-STAT TED OUTPUT VOL	·		a. CURRENT INITIAL	b. NEW A	N/A
12. CONFIGI	JRATION	ITEM (OR SYSTEM	I) TO WHICH E	CP APPLIES	I.		
13. DESCRIP	TION OF	REVISION			 		
Sheet 8:	Revisi Revisi Rev st Table Table Table	ons date column; on level block; atus of sheets;	add "96-09-00 add "A". for sheets 1 a und bounce no und bounce no bounce noise	and 8, add "A".		"1400" to "1600". "-1300" to "-1600" 600" to "700".	
14. THIS SE	CTION F	OR GOVERNMEN	T USE ONLY				
a. (X one)	X	(1) Existing docu	ment suppleme	nted by the NOR may	be used in manufac	cture.	
		(2) Revised docu	ment must be re	eceived before manu	facturer may incorpo	orate this change.	
		(3) Custodian of r	master docume	nt shall make above i	revision and furnish	revised document.	
b. ACTIVITY	AUTHO	RIZED TO APPRO	VE CHANGE F	OR GOVERNMENT	c. TYPED NAME (First, Middle Initial, La	ast)
DSCC-VA	C				Monica L. Poelki	ng	
d. TITLE				e. SIGNATURE			f. DATE SIGNED (YYMMDD)
Chief, Cus	tom Micr	oelectronics		Monica L. Poelkin	g		96-09-06
15a. ACTIVI	TY ACC	MPLISHING REV	ISION	b. REVISION COM	PLETED (Signature)		c. DATE SIGNED (YYMMDD)
DSCC-VAC Bernard J. Miesse					96-09-06		

								RF	EVISI	ONS							•			
LTR					DI	ESCR1	IPTIC	ON					D.	ATE	(YR-MO	-DA)		APPR	OVED	
REV										<u> </u>										
SHEET																				
REV						<u> </u>														
SHEET	15	16	17	18																
REV STAT	US			RE	V	<u> </u>														
OF SHEETS	S			SH	EET		1	2	3	4	5	6	7	8	9	10	11	12	13	14
PMIC N/A					ARED E	BY . Nguye	en			DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444										
STANDARD MICROCIRCUIT DRAWING		I		KED BY anh V.	Y . Nguye	en				CROC	IRC	UIT,	DI	GITA	AL,	FAS	г см	—— юs,		
THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE		NTS		OVED E	3Y L. Poe	lking			NOI TTI OUT	NINV CO PPUT LICO	ERT: MPA' VO	ING FIBI	THR Æ I	EE-S NPUT	STAT	E OI	LIMI	TED		
AMSC N/A				DRAW			L DATE .0-14			SIZ			E CO	DE			962-	9224		
				REVI	SION L	LEVEL					A	6	726							
					SHEE	Т	,	1		OF		18	;							

1. SCOPE

- 1.1 <u>Scope</u>. This drawing forms a part of a one part one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes Q and M) and space application (device class V), and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.
 - 1.2 PIN. The PIN shall be as shown in the following example:



- 1.2.1 RHA designator. Device class M RHA marked devices shall meet the MIL-I-38535 appendix A specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 <u>Device type(s)</u>. The device type(s) shall identify the circuit function as follows:

Device type	Generic number	<u>Circuit function</u>
01	54FCT623T	Octal bus transceiver with noninverting three-state outputs, TTL compatible inputs and limited output voltage swing
02	54FCT623AT	Octal bus transceiver with noninverting three-state outputs, TTL compatible inputs and limited output voltage swing
03	54FCT623CT	Octal bus transceiver with noninverting three-state outputs, TTL compatible inputs and limited output voltage swing

1.2.3 <u>Device class designator</u>. The device class designator shall be a single letter identifying the product assurance level as follows:

<u>Device class</u>	Device requirements documentation
М	Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883
Q or V	Certification and qualification to MIL-I-38535

1.2.4 <u>Case outline(s)</u>. The case outline(s) shall be as designated in MIL-STD-1835, and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
R	GDIP1-T20 or CDIP2-T20	20	Dual-in-line
S	GDFP2-F20 or CDFP3-F20	20	Flat pack
2	CQCC1-N2O	20	Square chip carrier

1.2.5 <u>Lead finish</u>. The lead finish shall be as specified in MIL-STD-883 (see 3.1 herein) for class M or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 2

1.	3	Absolute	maximum	ratings	1/	2/	3/

Supply voltage range (V _{CC})	-0.5 V dc to +7.0 V dc
DC input voltage range (V _{TN})	$-0.5 \text{ V dc to V}_{CC} + 0.5 \text{ V dc} \frac{4}{}$
DC output voltage range (\mathring{V}_{OUT})	-0.5 V dc to V_{CC} + 0.5 V dc $\frac{4}{4}$ /
DC input clamp current (I_{TV}) $(V_{TN} = -0.5 \text{ V})$	-20 mA
DC output clamp current (\hat{I}_{OK}) $(\hat{V}_{OUT}$ -0.5 V and +7.0 V)	±20 mA
DC output source current (I_{OH}) (per output)	-30 mA
DC output sink current (I _{OI}) (per output)	+70 mA
DC V _{CC} current (I _{CC})	±260 mA
Ground current (IGND)	+550 mA
Storage temperature range (T _{STG})	-65°C to +150°C
Case temperature under bias (Taras)	-65°C to +135°C
Lead temperature (soldering, 10 seconds)	+300°C
Thermal resistance, junction-to-case (Θ_{IC})	See MIL-STD-1835
Junction temperature (T_J) $\frac{3C}{1}$	+175°C
Maximum power dissipation (P _D)	500 mW

1.4 Recommended operating conditions. 2/3/

1.5 Digital logic testing for device classes Q and V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, test method 5012) - - - - - XX percent 5/

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, bulletin, and handbook</u>. Unless otherwise specified, the following specification, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

^{5/} Values will be added when they become available.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 3

^{1/} Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

^{2/} Unless otherwise noted, all voltages are referenced to GND.

 $[\]underline{3}$ / The limits for the parameters specified herein shall apply over the full specified V_{CC} range and case temperature range of -55°C to +125°C.

 $[\]underline{4}$ / For $V_{CC} \ge 6.5$ V, the upper limit on the range is limited to 7.0 V.

SPECIFICATION

MILITARY

MIL-I-38535 - Integrated Circuit

Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

MIL-STD-973 - Configuration Management.
MIL-STD-1835 - Microcircuit Case Outlines

BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specification, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-STD-883 (see 3.1 herein) for device class M and MIL-I-38535 for device classes Q and V and herein.
 - 3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein.
 - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.3 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.4 <u>Logic diagram</u>. The logic diagram shall be as specified on figure 3.
- 3.2.5 <u>Ground bounce load circuit and waveforms</u>. The ground bounce load circuit and waveforms shall be as specified on figure 4.
- 3.2.6 <u>Switching waveforms and test circuit</u>. The switching waveforms and test circuit shall be as specified on figure 5.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range. Test conditions for these specified characteristics and limits are as specified in table I.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 4

- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes Q and V shall be in accordance with MIL-I-38535.
- 3.5.1 <u>Certification/compliance mark</u>. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-I-38535.
- 3.6 <u>Certificate of compliance</u>. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.2 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.1 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change for device class M</u>. For device class M, notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-973.
- 3.9 <u>Verification and review for device class M</u>. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 37 (see MIL-I-38535, appendix A).
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. For device class M, sampling and inspection procedures shall be in accordance with MIL-STD-883 (see 3.1 herein). For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.
- 4.2 <u>Screening</u>. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.
 - 4.2.1 Additional criteria for device class M.
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
 - (2) $T_{\Delta} = +125$ °C, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 5

TABLE I. <u>Electrical performance characteristics</u>.

			per formane	c charact	cer iscre.	2.			
Test and MIL-STD-883 test method 1/	Symbol	Test condition $-55^{\circ}C \leq T_{C} \leq +4.5 \text{ V} \leq V_{CC}$	ions 2/ ≤ +125°C	Device type	v _{cc}	Group A subgroups	Lim	its <u>3</u> /	Unit
		unless otherwis	e specified				Min	Max	
High level output voltage (A and B bus)	V _{OH1} <u>4</u> /	For all inputs affecting output	I _{OH} = -300 μA	All	4.5 V	1, 2, 3	2.7	v _{cc} -0.5	V
3006	v _{oH2}	under test V _{IN} = 2.0 V or	1 _{OH} = -6 mA]		1, 2, 3	2.4	v _{cc} -0.5	1
	V _{OH3}	0.8 V For all other	I _{OH} = -12 mA			1, 2, 3	2.0	V _{CC} -0.5]
Low level output voltage (A bus) 3007	V _{OL} 1	inputs V _{IN} = V _{CC} or GND	I _{OL} = 300 μA	ALL	4.5 V	1, 2, 3		0.2	V
	V _{OL2}	_	I _{OL} = 32 mA			1, 2, 3		0.50	l
Low level output voltage (B bus) 3007	V ₀ L3		I _{OL} = 300 μA	All	4.5 V	1, 2, 3		0.2	V
	V _{OL4}		I _{OL} = 48 mA			1, 2, 3		0.55]
Negative input clamp voltage 3022	v _{IC-}	For input under tes	For input under test, I _{IN} = -18 mA		4.5 V	1, 2, 3		-1.2	v
Three-state output leakage current	I _{OZH} 5/ <u>6</u> /	OEAB or OEBA = 2.0 V or 0.8 V	v _{out} = v _{cc}	ALL	5.5 V	1, 2		1.0	μΑ
high 3021	2, 0,	For all other inputs				3		10.0	
Three-state output leakage current	IOZL 5/ <u>6</u> /	V _{IN} = V _{CC} or GND	V _{OUT} = GND	All	5.5 V	1, 2		-1.0	μΑ
low 3020						3		-10.0	1
Input current high 3010	I _{IH}	For input under	Control	ALL	5.5 V	1, 2		1.0	μΑ
55,0		test, V _{IN} = V _{CC} For all other	inputs			3		5.0]
		inputs V _{IN} = V _{CC} or GND	I/O pins			1, 2		2.0	
						3		15.0	
Input current low 3009	IIL	For input under	Control inputs	ALL	5.5 V	1, 2		-1.0	μΑ
3307		test, V _{IN} = GND For all other	inputs			3		-5.0]
		inputs V _{IN} = V _{CC} or GND	I/O pins			1, 2		-2.0	
_						3		-15.0	<u> </u>
Output short circuit current 3011	I _O S <u>7</u> /	For all inputs, V _{IN} V _{OUT} = GND	= V _{CC} or GND	All	5.5 V	1, 2, 3	-60	-225	mA
Dynamic power supply current	1 4/8/	Outputs open		All	5.5 V	4, 5, 6		0.25	mA/ MHz●Bit

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 6

 ${\sf TABLE\ I.}\quad \underline{\sf Electrical\ performance\ characteristics}\ -\ {\sf Continued.}$

Test and MIL-STD-883	Symbol	Test condition -55°C ≤ T _C ≤		Device type	v _{cc}	Group A subgroups	Limi	ts <u>3</u> /	Unit
test method <u>1</u> /		-55°C ≤ T _C ≤ +125 ^o C +4.5 V ≤ V _{CC} ≤ +5.5 V unless otherwise specified					Min	Max	
Off-state leakage current	1 ₉ FF	For input or output un V _{IN} or V _{OUT} = 4.5 V		All	0.0 V	1, 2		1.0	μА
		All other pins at 0.0	V			3		5.0	
Quiescent supply current delta, TTL input level 3005	ΔΙ _{CC}	For input under test V _{IN} = 3.4 V For all other inputs V _{IN} = V _{CC} or GND		All	5.5 V	1, 2, 3		2.0	mA
Quiescent supply current, outputs high 3005	^I ссн	OEAB = V _{CC} , OEBA = GND For all other inputs V _{IN} = V _{CC} or GND		ALL	5.5 V	1, 2, 3		1.5	mA
Quiescent supply current, outputs low 3005	ICCL			All	5.5 V	1, 2, 3		1.5	mA
Quiescent supply current, outputs disabled 3005	I _{CCZ}	OEAB = GND, OEBA = V _{CC} For all other inputs V _{IN} = V _{CC} or GND		All	5.5 V	1, 2, 3		1.5	mA
Total supply current	^I сст1 <u>11</u> /	Outputs_open OEAB = OEBA = GND One bit toggling f; = 10 MHz	For switching inputs V _{IN} = V _{CC} or GND	ALL	5.5 V	4, 5, 6		4.0	mA
		50% duty cycle For nonswitching input, V _{IN} = V _{CC} or GND	For switching inputs V _{IN} = 3.4 V or GND			4, 5, 6		5.0	
	1 4/217/	Outputs <u>ope</u> n OEAB = OEBA = GND Eight bits toggling f _i = 2.5 MHz	For switching inputs VIN = VCC Or GND	All	5.5 V	4, 5, 6		6.5	
		50% duty cycle For nonswitching input, V _{IN} = V _{CC} or GND	For switching inputs VIN = 3.4 V OR GND		:	4, 5, 6		14.5	
Input capacitance 3012	c _{IN} 12	T _C = +25°C See 4.4.1b		All	GND	4		10.0	pF
I/O capacitance 3012	C _I /O 12/			All	GND	4		12.0	pF

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 7

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test and Symbol MIL-STD-883		Test conditions $\frac{2}{}$ / -55°C \leq T _C \leq +125°C	Device type	v _{cc}	Group A subgroups	Limi	ts <u>3</u> /	Unit
test method <u>1</u> /		$+4.5 \text{ V} \leq \text{V}_{CC}^{\circ} \leq +5.5 \text{ V}$ unless otherwise specified			- ,	Min	Max	
Low level ground bounce noise	V _{OLP} 127 13/	V _{IH} = 3.0 V, V _{IL} = 0.0 V T _A = +25°C	All	5.0 V	4	-	1400	mV
94.	ν _{οιν} <u>12</u> 7 <u>13</u> /	Sêe figure 4			4		-1300	
High level V _{CC} bounce noise	v _{OHP} <u>12</u> / <u>13</u> /		All	5.0 V	4		600	m∨
	v _{OHV} 12/				4		-550	
Functional test 3014	<u>14</u> /	V _{IH} = 2.0 V, V _{IL} = 0.8 V Verify output V _O	All	4.5 V	7, 8	L	н	
		See 4.4.1c		5.5 V	7, 8	L	н	
Propagation delay time, An to Bn	t _{PLH1}	$C_L = 50 \text{ pF minimum}$ $R_L = 500\Omega$	01	4.5 V	9, 10, 11	1.5	9.0	ns
3003	15/L1	See figure 5	02		9, 10, 11	1.5	6.3	
			03		9, 10, 11	1.5	5.4	
Propagation delay time, Bn to An	tPLH2/		01	4.5 V	9, 10, 11	1.5	9.5	ns
3003	15/L2		02		9, 10, 11	1.5	6.3	
			03		9, 10, 11	1.5	5.4	
Propagation delay time, output	t _{PZH1} /		01	4.5 V	9, 10, 11	1.5	10.0	ns
enable, OEBA to	† _P ZL1 15		02		9, 10, 11	1.5	8.0	
3003			03		9, 10, 11	1.5	6.9	
Propagation delay time, output	t _{PHZ1} /		01	4.5 V	9, 10, 11	1.5	9.0	ns
disable, OEBA to	15/21		02		9, 10, 11	1.5	7.4	
An 3003			03		9, 10, 11	1.5	6.4	
Propagation delay	t _{PZH2}		01	4.5 V	9, 10, 11	1.5	10.5	ns
time, output enable, OEAB to	157L2		02		9, 10, 11	1.5	8.0	
Bn 3003			03		9, 10, 11	1.5	6.9	
Propagation delay	t _{PHZ2} ,		01	4.5 V	9, 10, 11	1.5	9.0	ns
time, output disable, OEAB to Bn	15/22		02		9, 10, 11	1.5	7.4	
3003			03	•	9, 10, 11	1.5	6.4	

See footnotes on next sheet.

STANDARD MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-92242
		REVISION LEVEL	SHEET 8

TABLE I. Electrical performance characteristics - Continued.

- For tests not listed in the referenced MIL-STD-883 (e.g. ΔI_{CC}), utilize the general test procedure of 883 under the conditions listed herein.
- Each input/output, as applicable, shall be tested at the specified temperature, for the specified limits, to the tests in table I herein. Output terminals not designated shall be high level logic, low level logic, or open, except for all I_{CC} and ΔI_{CC} tests, the output terminals shall be open. When performing these tests, the current meter shall be placed in the circuit such that all current flows through the meter.
- For negative and positive voltage and current values, the sign designates the potential difference in reference to GND and the direction of current flow, respectively; and the absolute value of the magnitude, not the sign, is relative to the minimum and maximum limits, as applicable, listed herein. All devices shall meet or exceed the limits specified in table I at 4.5 V \leq V_{CC} \leq 5.5 V.
- This parameter is guaranteed, if not tested, to the limits specified in table I herein.
- Three-state output conditions are required.
- This test may be performed using V_{IH} = 3.0 V. When V_{IH} = 3.0 V is used, the test is guaranteed for V_{IH} = 2.0 V. This test is guaranteed by the I_{IL} and I_{IH} test.
- Not more than one output should be tested at a time. The duration of the test should not exceed one second.
- I_{CCD} may be verified by the following equation:

$$I_{CCD} = \frac{I_{CCT} - I_{CC} - D_H N_T \Delta I_{CC}}{f_{CP}/2 + f_i N_i}$$

where I_{CCT} , I_{CC} (I_{CCL} or I_{CCH} in table I), and ΔI_{CC} shall be the measured values of these parameters, for the device under test, when tested as described in table I, herein. The values for D_H , N_T , f_{CP} , f_i , and N_i shall be as listed in the test conditions column for I_{CCT} in table I, herein.

- 9/ For Iner testing, test each input and output.
- $\underline{10}$ / This test may be performed either one input at a time (preferred method) or with all input pins simultaneously at $V_{IN} = V_{CC} - 2.1 \text{ V}$ (alternate method). Classes Q and V shall use the preferred method. When the test is performed uŝing the alternate test method, the maximum limit is equal to the number of inputs at a high TTL input level times 1.5 mA; and the preferred method and limits are guaranteed.
- $11/I_{CCT}$ is calculated as follows:

$$I_{CCT} = I_{CC} + D_H N_T \Delta I_{CC} + I_{CCD} (f_{CP}/2 + f_i N_i)$$

 I_{CC} = Quiescent supply current (any I_{CCL} or I_{CCH}) D_{H} = Duty cycle for TTL inputs at 3.4 V

D_H = Duty cycle rolling N_T = Number of TTL inputs at 3.4 V

 Δi_{CC} = Quiescent supply current delta, TTL inputs at 3.4 V

 I_{CCD} = Dynamic power supply current caused by an input transition pair (HLH or LHL)

 f_{CP} = Clock frequency for registered devices (f_{CP} = 0 for nonregistered devices) f_i = Input frequency N_i = Number of inputs at f_i

 $\underline{12}/$ This test is required only for group A testing; see 4.4.1 herein.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 9

TABLE I. <u>Electrical performance characteristics</u> - Continued.

13/ This test is for qualification only. Ground and V_{CC} bounce tests are performed on a non-switching (quiescent) output and are used to measure the magnitude of induced noise caused by other simultaneously switching outputs. The test is performed on a low noise bench test fixture. For the device under test, all outputs shall be loaded with 500Ω of load resistance and a minimum of 50 pF of load capacitance (see figure 4). Only chip capacitors and resistors shall be used. The output load components shall be located as close as possible to the device outputs. It is suggested, that whenever possible, this distance be kept to less than 0.25 inches. Decoupling capacitors shall be placed in parallel from V_{CC} to ground. The values of these decoupling capacitors shall be determined by the device manufacturer. The low and high level ground and V_{CC} bounce noise is measured at the quiet output using a 1 GHz minimum bandwidth oscilloscope with a 50Ω input impedance.

The device inputs shall be conditioned such that all outputs are at a high nominal V_{OH} level. The device inputs shall then be conditioned such that they switch simultaneously and the output under test remains at V_{OH} as all other outputs possible are switched from V_{OH} to V_{OL} . V_{OHV} and V_{OHP} are then measured from the nominal V_{OH} level to the largest negative and positive peaks, respectively (see figure 4). This is then repeated with the same outputs not under test switching from V_{OI} to V_{OH} .

The device inputs shall be conditioned such that all outputs are at a low nominal V_{OL} level. The device inputs shall then be conditioned such that they switch simultaneously and the output under test remains at V_{OL} as all other outputs possible are switched from V_{OL} to V_{OH} . V_{OLP} and V_{OLV} are then measured from the nominal V_{OL} level to the largest positive and negative peaks, respectively (see figure 4). This is then repeated with the same outputs not under test switching from V_{OH} to V_{OL} .

- $\underline{14}/$ Tests shall be performed in sequence, attributes data only. Functional tests shall include the truth table and other logic patterns used for fault detection. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2 herein. Functional tests shall be performed in sequence as approved by the qualifying activity on qualified devices. For outputs, L < 1.5 V, H \geq 1.5 V.
- 15/ AC limits at V_{CC} = 5.5 V are equal to the limits at V_{CC} = 4.5 V and guaranteed by testing at V_{CC} = 4.5 V. Minimum propagation delay time limits for V_{CC} = 4.5 V and 5.5 V are guaranteed, if not tested, to the limits specified in table I, herein. For propagation delay tests, all paths must be tested.

STANDARD
MICROCIRCUIT DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

SIZE A		5962-92242
	REVISION LEVEL	SHEET 10

Device types	01, 02, 03	
Case outlines	R, S, and 2	
Terminal number	Terminal symbol	
1	OEAB	
2	A1	
3	A2	
4	A3	
5	Α4	
6	A5	
7	A6	
8	A7	
9	A8	
10	GND	
11	В8	
12	в7	
13	В6	
14	В5	
15	В4	
16	В3	
17	В2	
18	В1	
19	OEBA	
20	v _{cc}	

Terminal descriptions				
Terminal symbol	Description			
An (n = 1 to 8)	A bus inputs or three-state outputs			
Bn (n = 1 to 8)	B bus inputs or three-state outputs			
OEAB/OEBA	A-to-B/B-to-A output enable control input			

FIGURE 1. Terminal connections.

STANDARD MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-92242
		REVISION LEVEL	SHEET 11

Device types 01, 02, 03					
Inputs					
OEBA	OEAB	Operation			
L	L	B data to A bus			
L	н	B data to A bus, A data to B bus			
н	L	Isolation			
н	н	A data to B bus			

H = High voltage level L = Low voltage level

FIGURE 2. Truth table.

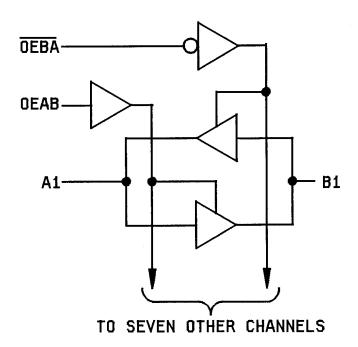
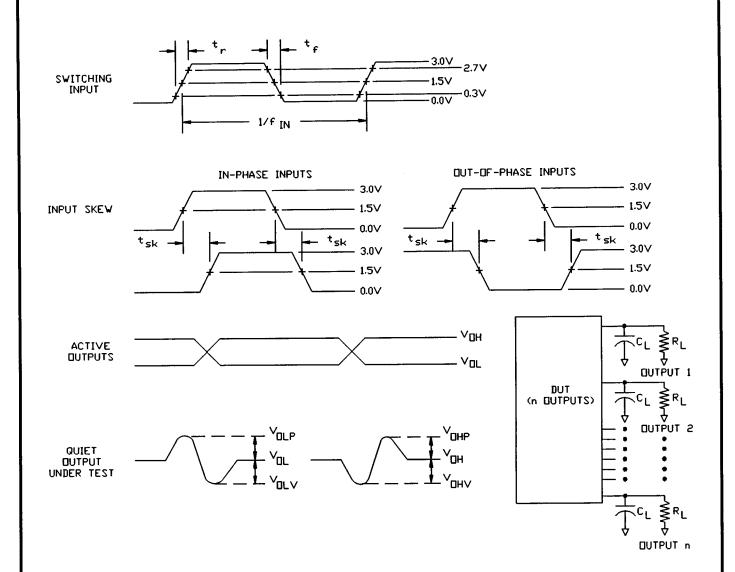


FIGURE 3. Logic diagram.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 12



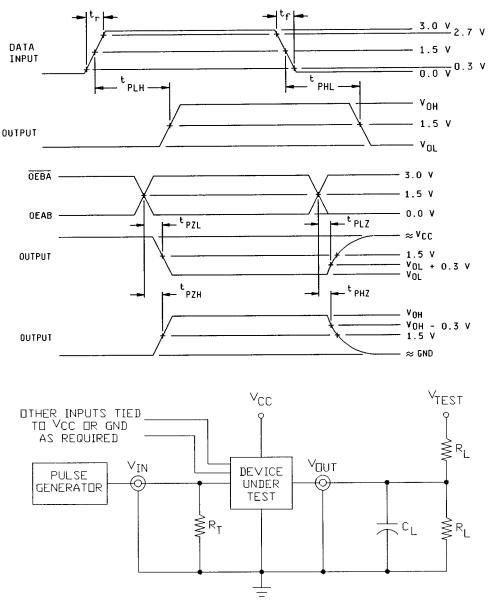
NOTES:

- 1. C_ includes a 47 pF chip capacitor (-0 percent, +20 percent) and at least 3 pF of equivalent capacitance from the test jig and probe.
- 2. R_1 = 450 Ω ±1 percent, chip resistor in series with a 50 Ω termination. For monitored outputs, the 50 Ω termination shall be the 50Ω characteristic impedance of the coaxial connector to the oscilloscope.
- 3. Input signal to the device under test:

 - a. $V_{IN} = 0.0 \text{ V}$ to 3.0 V; duty cycle = 50 percent; $f_{IN} \ge 1 \text{ MHz}$. b. t_r , $t_f = 3 \text{ ns } \pm 1.0 \text{ ns}$. For input signal generators incapable of maintaining these values of t_r and t_f , the 3.0 ns limit may be increased up to 10 ns, as needed, maintaining the $\pm 1.0 \text{ ns}$ tolerance and guaranteeing the results at 3.0 ns $\pm 1.0 \text{ ns}$; skew between any two switching inputs signals (t_{sk}) : $\le 250 \text{ ps}$.

FIGURE 4. Ground bounce load circuit and waveforms.

STANDARD MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-92242
		REVISION LEVEL	SHEET 13



NOTES:

- When measuring t_{PLZ} and t_{PZL}: V_{TEST} = 7.0 V.
 When measuring t_{PHZ}, t_{PZH}, t_{PLH}, and t_{PHL}: V_{TEST} = open.
 The t_{PZL} and t_{PLZ} reference waveform is for the output under test with internal conditions such that the output is at V_{OL} except when disabled by the output enable control. The t_{PZH} and t_{PHZ} reference waveform is for the output under test with internal conditions such that the output is at V_{OH} except when disabled by the output enable control.
- c_L = 50 pF minimum or equivalent (includes test jig and probe capacitance).
- 5. $R_L^L = 500\Omega$ or equivalent.
- $R_T^L = 50\Omega$ or equivalent.
- Input signal from pulse generator: V_{IN} = 0.0 V to 3.0 V; PRR \leq 10 MHz; t_f \leq 2.5 ns; t_f \leq 2.5 ns; t_r and t_f shall be measured from 0.3 V to 2.7 V and from 2.7 V to 0.3 V, respectively; duty cycle = 50 percent.
- 8. Timing parameters shall be tested at a minimum input frequency of 1 MHz.
- 9. The outputs are measured one at a time with one transition per measurement.

FIGURE 5. Switching waveforms and test circuit.

STANDARD MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-92242
		REVISION LEVEL	SHEET 14

TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, TM 5005, table I)	Subgroups (in accordance with MIL-I-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)		1	1
Final electrical parameters (see 4.2)	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 <u>1</u> /	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 <u>1</u> /	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 <u>2</u> /
Group A test requirements (see 4.4)	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 2, 3, 4, 5, 6	1, 2, 3, 4, 5, 6	1, 2, 3, 4, 5, 6 7, 8, 9, 10, 11
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	1, 4, 7, 9	1, 4, 7, 9	1, 4, 7, 9

 $[\]underline{1}$ / PDA applies to subgroups 1 and 4 (i.e., I_{CCT} only).

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535 and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535.
- 4.3 <u>Qualification inspection for device classes Q and V.</u> Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.3.1 <u>Electrostatic discharge sensitivity qualification inspection</u>. Electrostatic discharge sensitivity (ESDS) testing shall be performed in accordance with MIL-STD-883, method 3015. ESDS testing shall be measured only for initial qualification and after process or design changes which may affect ESDS classification.
- 4.4 <u>Conformance inspection</u>. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

STANDARD MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-92242
		REVISION LEVEL	SHEET 15

²/ PDA applies to subgroups 1, 4, and 7.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. c_{IN} and $c_{I/O}$ shall be measured only for initial qualification and after process or design changes which may affect capacitance. c_{IN} and $c_{I/O}$ shall be measured between the designated terminal and GND at a frequency of 1 MHz. For c_{IN} and $c_{I/O}$, test all applicable pins on five devices with zero failures.

For $c_{\rm IN}$ and $c_{\rm I/O}$, a device manufacturer may qualify devices by functional groups. A specific functional group shall be composed of function types, that by design, will yield the same capacitance values when tested in accordance with table I herein. The device manufacturer shall set a functional group limit for the $c_{\rm IN}$ and $c_{\rm I/O}$ tests. The device manufacturer may then test one device function from a functional group to the limits and conditions specified herein. All other device functions in that particular functional group shall be guaranteed, if not tested, to the limits and conditions specified in table I herein. The device manufacturer shall submit to DESC-EC the device functions listed in each functional group and the test results for each device tested.

- c. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table in figure 2 herein. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2 herein. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device; these tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).
- d. Ground and V_{CC} bounce tests are required for all device classes. These tests shall be performed only for initial qualification, after process or design changes which may affect the performance of the device, and any changes to the test fixture. V_{OLP}, V_{OLV}, V_{OHP}, and V_{OHV} shall be measured for the worst case outputs of the device. All other outputs shall be guaranteed, if not tested, to the limits established for the worst case outputs. The worst case outputs tested are to be determined by the manufacturer. Test 5 devices assembled in the worst case package type supplied to this document. All other package types shall be guaranteed, if not tested, to the limits established for the worst case package. The package type to be tested shall be determined by the manufacturer. The device manufacturer will submit to DESC-EC data that shall include all measured peak values for each device tested and detailed oscilloscope plots for each V_{OLP}, V_{OLY}, V_{OHP}, and V_{OHV} from one sample part per function. The plot shall contain the waveforms of both a switching output and the output under test.

Each device manufacturer shall test product on the fixtures they currently use. When a new fixture is used, the device manufacturer shall inform DESC-EC of this change and test the 5 devices on both the new and old test fixtures. The device manufacturer shall then submit to DESC-EC data from testing on both fixtures that shall include all measured peak values for each device tested and detailed oscilloscope plots for each V_{OLP} , V_{OLP} , and V_{OHP} , from one sample part per function. The plot shall contain the waveforms of both a switching output and the output under test.

For V_{OLP} , V_{OHP} , and V_{OHP} , a device manufacturer may qualify devices by functional groups. A specific functional group shall be composed of function types, that by design, will yield the same test values when tested in accordance with table I herein. The device manufacturer shall set a functional group limit for the V_{OLP} , V_{OHP} , and V_{OHP} tests. The device manufacturer may then test one device function from a functional group to the limits and conditions specified herein. All other device functions in that particular functional group shall be guaranteed, if not tested, to the limits and conditions specified in table I herein. The device manufacturer shall submit to DESC-EC the device functions listed in each functional group and the test results, along with the oscilloscope plots, for each device tested.

- 4.4.2 <u>Group C inspection</u>. The group C inspection end-point electrical parameters shall be as specified in table II herein.
 - 4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:
 - a. Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
 - b. $T_A = +125$ °C, minimum.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 16

- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 4.4.2.2 <u>Additional criteria for device classes Q and V</u>. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The test circuit shall be maintained under document revision level control of the device manufacturer's TRB in accordance with MIL-I-38535 and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
- 4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes Q and V shall be M, D, R, and H and RHA levels for device class M shall be M and D.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-I-38535, appendix A, for the RHA level being tested. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-I-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at T_A = +25°C ±5°C, after exposure, to the subgroups specified in table II herein.
 - c. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.
 - 4.5 Methods of inspection. Methods of inspection shall be specified as follows:
- 4.5.1 <u>Voltage and current</u>. Unless otherwise specified, all voltages given are referenced to the microcircuit GND terminal. Currents given are conventional current and positive when flowing into the referenced terminal.
 - PACKAGING
- 5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-STD-883 (see 3.1 herein) for device class M and MIL-I-38535 for device classes Q and V.
 - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
 - 6.1.2 <u>Substitutability</u>. Device class Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.3 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444-5270, or telephone (513) 296-5377.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92242
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET 17

6.5 Abbreviations, symbols, and definit in MIL-I-38535 and MIL-STD-1331, and as fo	ions. The abbrev	iations, symbols	, and definiti	ons used her	rein are defined
<pre>In MIL-I-38535 and MIL-STD-1331, and as follows:</pre> GND Ground zero voltage potential. I_CC Quiescent supply current. I_IL Input current low. I_IH Input current high. T_C Case temperature. T_A Ambient temperature. V_CC Positive supply voltage. C_IN Input terminal-to-GND capacitance. C_I/O Input/output terminal-to-GND capacitance. V_IC Negative input clamp voltage.					
6.6 One part - one part number system. allow for transitions between identical ge (MIL-H-38534, MIL-I-38535, and 1.2.1 of MI three military requirements documents reprupgraded military product from one class the Original Equipment Manufacturer (OEM), establishing a one part number system cove available for a given generic device to me criteria.	neric devices covo L-STD-883) without esent different c evel to another, t that was contrac- ring all three do	ered by the three t the necessity that lass levels, and the benefits of the tually locked into cuments, the OEM	e major microc for the genera previously wh the upgraded p to the origina can acquire t	ircuit requi tion of uniq en a device roduct were l unique PIN o the highes	rements documents ue PIN's. The manufacturer unavailable to . By t class level
Military documentation format	Example PIN under new syste		cturing listing	Document <u>listing</u>	
New MIL-H-38534 Standard Microcircuit Drawings	5962-XXXXXZZ(H or	K)YY QML-385	534	MIL-BUL-103	
New MIL-I-38535 Standard Microcircuit Drawings	5962-XXXXXZZ(Q or	V)YY QML-385	535	MIL-BUL-103	
New 1.2.1 of MIL-STD-883 Standard Microcircuit Drawings.	5962-XXXXXZZ(M)YY	MIL-BU	103	MIL-BUL-103	
6.7 Sources of supply.					
6.7.1 <u>Sources of supply for device clas</u> QML-38535. The vendors listed in QML-3853 have agreed to this drawing.	ses Q and V. Sour 5 have submitted a	rces of supply fo a certificate of	or device clas compliance (s	ses Q and V se 3.6 herei	are listed in n) to DESC-EC and
6.7.2 <u>Approved sources of supply for de</u> MIL-BUL-103. The vendors listed in MIL-BU herein) has been submitted to and accepted	L-103 have agreed	proved sources of to this drawing	f supply for c and a certifi	lass M are l cate of comp	isted in liance (see 3.6
•	~,				
STANDARD	-	SIZE A			5962-92242
MICROCIRCUIT DRAWING DEFENSE ELECTRONICS SUPPLY DAYTON, OHIO 45444	CENTER		REVISION	LEVEL	SHEET

18

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN

DATE: 94-10-14

Approved sources of supply for SMD 5962-92242 are listed below for immediate acquisition only and shall be added to MIL-BUL-103 during the next revision. MIL-BUL-103 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DESC-EC. This bulletin is superseded by the next dated revision of MIL-BUL-103.

Standardized military drawing PIN	Vendor CAGE number	Vendor similar PIN <u>1</u> /
5962-9224201MRX	61772	IDT54FCT623TDB
5962-9224201MSX	61772	IDT54FCT623TEB
5962-9224201M2X	61772	IDT54FCT623TLB
5962-9224202MRX	61772	IDT54FCT623ATDB
5962-9224202MSX	61772	IDT54FCT623ATEB
5962-9224202M2X	61772	IDT54FCT623ATLB
5962-9224203MRX	61772	IDT54FCT623CTDB
5962-9224203MSX	61772	IDT54FCT623CTEB
5962-9224203M2X	61772	IDT54FCT623CTLB

1/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

61772

Vendor name and address

Integrated Devices Technology Inc 3236 Scott Boulevard P.O. Box 58015 Santa Clara, CA 95052

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.